

Low Noise/Low Power/SPI Bus/256 Taps

Data Sheet

April 18, 2006

FN8165.2

X<u>925</u>0

Quad Digitally Controlled Potentiometers (XDCP™)

FEATURES

- · Four potentiometers in one package
- 256 resistor taps/pot 0.4% resolution
- SPI serial interface
- Wiper resistance, 40Ω typical @ V_{CC} = 5V
- · Four nonvolatile data registers for each pot
- Nonvolatile storage of wiper position
- Standby current < 5µA max (total package)
- Power supplies
 - -V_{CC} = 2.7V to 5.5V
 - —V+ = 2.7V to 5.5V
 - —V– = -2.7V to -5.5V
- 100k Ω , 50k Ω total pot resistance
- · High reliability
 - Endurance 100,000 data changes per bit per register
 - -Register data retention 100 years
- 24 Ld SOIC, 24 Ld TSSOP
- Dual supply version of X9251
- Pb-free plus anneal available (RoHS compliant)

BLOCK DIAGRAM

DESCRIPTION

The X9250 integrates 4 digitally controlled potentiometers (XDCP) on a monolithic CMOS integrated circuit.

The digitally controlled potentiometer is implemented using 255 resistive elements in a series array. Between each element are tap points connected to the wiper terminal through switches. The position of the wiper on the array is controlled by the user through the SPI bus interface. Each potentiometer has associated with it a volatile Wiper Counter Register (WCR) and 4 nonvolatile Data Registers (DR0:DR3) that can be directly written to and read by the user. The contents of the WCR controls the position of the wiper on the resistor array though the switches. Power up recalls the contents of DR0 to the WCR.

The XDCP can be used as a three-terminal potentiometer or as a two-terminal variable resistor in a wide variety of applications including control, parameter adjustments, and signal processing.



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Ordering Information

PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	POTENTIOMETER ORGANIZATION (kΩ)	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
X9250TS24*	X9250TS	5 ±10%	100	0 to 70	24 Ld SOIC (300mil)	M24.3
X9250TS24Z* (Note)	X9250TS Z			0 to 70	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250TS24I*	X9250TS I	-		-40 to 85	24 Ld SOIC (300mil)	M24.3
X9250TS24IZ* (Note)	X9250TS ZI			-40 to 85	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250TV24	X9250TV			0 to 70	24 Ld TSSOP (4.4mm)	MDP0044
X9250TV24Z (Note)	X9250TV Z			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250TV24I	X9250TV I			-40 to 85	24 Ld TSSOP (4.4mm)	MDP0044
X9250TV24IZ (Note)	X9250TV ZI			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250US24*	X9250US	-	50	0 to 70	24 Ld SOIC (300mil)	M24.3
X9250US24Z* (Note)	X9250US Z			0 to 70	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250US24I*	X9250US I			-40 to 85	24 Ld SOIC (300mil)	M24.3
X9250US24IZ* (Note)	X9250US ZI			-40 to 85	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250UV24	X9250UV			0 to 70	24 Ld TSSOP (4.4mm)	MDP0044
X9250UV24Z (Note)	X9250UV Z			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250UV24I	X9250UV I			-40 to 85	24 Ld TSSOP (4.4mm)	MDP0044
X9250UV24IZ (Note)	X9250UV ZI			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250TS24-2.7*	X9250TS F	-2.7 to 5.5	100	0 to 70	24 Ld SOIC (300mil)	M24.3
X9250TS24Z-2.7* (Note)	X9250TS ZF			0 to 70	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250TS24I-2.7*	X9250TS G			-40 to 85	24 Ld SOIC (300mil)	M24.3
X9250TS24IZ-2.7* (Note)	X9250TS ZG			-40 to 85	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250TV24-2.7	X9250TV F			0 to 70	24 Ld TSSOP (4.4mm)	MDP0044
X9250TV24Z-2.7 (Note)	X9250TV ZF			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250TV24I-2.7	X9250TV G			-40 to 85	24 Ld TSSOP (4.4mm)	MDP0044
X9250TV24IZ-2.7 (Note)	X9250TV ZG			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250US24-2.7*	X9250US F		50	0 to 70	24 Ld SOIC (300mil)	M24.3
X9250US24Z-2.7* (Note)	X9250US ZF			0 to 70	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250US24I-2.7*	X9250US G			-40 to 85	24 Ld SOIC (300mil)	M24.3

Ordering Information (Continued)

PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	POTENTIOMETER ORGANIZATION ($k\Omega$)	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
X9250US24IZ-2.7* (Note)	X9250US ZG	-2.7 to 5.5	50	-40 to 85	24 Ld SOIC (300mil) (Pb-free)	M24.3
X9250UV24-2.7	X9250UV F			0 to 70	24 Ld TSSOP (4.4mm)	MDP0044
X9250UV24Z-2.7 (Note)	X9250UV ZF			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044
X9250UV24I-2.7	X9250UV G			-40 to 85	24 Ld TSSOP (4.4mm)	MDP0044
X9250UV24IZ-2.7 (Note)	X9250UV ZG			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)	MDP0044

*Add "T1" suffix for tape and reel.

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

PIN DESCRIPTIONS

Serial Output (SO)

SO is a serial data output pin. During a read cycle, data is shifted out on this pin. Data is clocked out by the falling edge of the serial clock.

Serial Input

SI is the serial data input pin. All opcodes, byte addresses and data to be written to the pots and pot registers are input on this pin. Data is latched by the rising edge of the serial clock.

Serial Clock (SCK)

The SCK input is used to clock data into and out of the X9250.

Chip Select (CS)

When \overline{CS} is HIGH, the X9250 is deselected and the SO pin is at high impedance, and (unless an internal write cycle is underway) the device will be in the standby state. \overline{CS} LOW enables the X9250, placing it in the active power mode. It should be noted that after a power-up, a HIGH to LOW transition on \overline{CS} is required prior to the start of any operation.

Hold (HOLD)

HOLD is used in conjunction with the \overline{CS} pin to select the device. Once the part is selected and a serial sequence is underway, HOLD may be used to pause the serial communication with the controller without resetting the serial sequence. To pause, HOLD must be brought LOW while SCK is LOW. To resume communication, HOLD is brought HIGH, again while SCK is LOW. If the pause feature is not used, HOLD should be held HIGH at all times.

Device Address (A₀ - A₁)

The address inputs are used to set the least significant 2 bits of the 8-bit slave address. A match in the slave address serial data stream must be made with the address input in order to initiate communication with the X9250. A maximum of 4 devices may occupy the SPI serial bus.

Potentiometer Pins

$V_{H}/R_{H}~(V_{H0}/R_{H0}$ - $V_{H3}/R_{H3}),~V_{L}/R_{L}~(V_{L0}/R_{L0}$ - $V_{L3}/R_{L3})$

The R_{H} and R_{L} pins are equivalent to the terminal connections on a mechanical potentiometer.

$V_W/R_W (V_{W0}/R_{W0} - V_{W3}/R_{W3})$

The wiper pins are equivalent to the wiper terminal of a mechanical potentiometer.

Hardware Write Protect Input (WP)

The $\overline{\text{WP}}$ pin when LOW prevents nonvolatile writes to the Data Registers.

Analog Supplies (V+, V-)

The analog supplies V+, V- are the supply voltages for the XDCP analog section.

PIN CONFIGURATION



PIN NAMES

Symbol	Description
SCK	Serial Clock
SI, SO	Serial Data
A ₀ -A ₁	Device Address
$V_{H0}/R_{H0}V_{H3}/R_{H3}, V_{L0}/R_{L0}V_{L3}/R_{L3}$	Potentiometer Pins (terminal equivalent)
V _{W0} /R _{W0} _V _{W3} /R _{W3}	Potentiometer Pins (wiper equivalent)
WP	Hardware Write Protection
V+,V-	Analog Supplies
V _{CC}	System Supply Voltage
V _{SS}	System Ground
NC	No Connection

DEVICE DESCRIPTION

Serial Interface

The X9250 supports the SPI interface hardware conventions. The device is accessed via the SI input with data clocked in on the rising SCK. \overline{CS} must be LOW and the HOLD and \overline{WP} pins must be HIGH during the entire operation.

The SO and SI pins can be connected together, since they have three state outputs. This can help to reduce system pin count.

Array Description

The X9250 is comprised of four resistor arrays. Each array contains 255 discrete resistive segments that are connected in series. The physical ends of each array are equivalent to the fixed terminals of a mechanical potentiometer (V_H/R_H and V_L/R_L inputs).

At both ends of each array and between each resistor segment is a CMOS switch connected to the wiper (V_W/R_W) output. Within each individual array only one switch may be turned on at a time.

These switches are controlled by a Wiper Counter Register (WCR). The 8 bits of the WCR are decoded to select, and enable, one of 256 switches.

Wiper Counter Register (WCR)

The X9250 contains four Wiper Counter Registers, one for each XDCP potentiometer. The WCR is equivalent to a serial-in, parallel-out register/counter with its outputs decoded to select one of 256 switches along its resistor array. The contents of the WCR can be altered in four ways: it may be written directly by the host via the write Wiper Counter Register instruction (serial load); it may be written indirectly by transferring the contents of one of four associated Data Registers via the XFR Data Register or Global XFR Data Register instructions (parallel load); it can modified one step at a time by the be increment/decrement instruction. Finally, it is loaded with the contents of its Data Register zero (DR0) upon power-up.

The Wiper Counter Register is a volatile register; that is, its contents are lost when the X9250 is powereddown. Although the register is automatically loaded with the value in R0 upon power-up, this may be different from the value present at power-down.

Data Registers

Each potentiometer has four 8-bit nonvolatile Data Registers. These can be read or written directly by the host. Data can also be transferred between any of the four Data Registers and the associated Wiper Counter Register. All operations changing data in one of the Data Registers is a nonvolatile operation and will take a maximum of 10ms.

If the application does not require storage of multiple settings for the potentiometer, the Data Registers can be used as regular memory locations for system parameters or user preference data.

Data Register Detail

(MSB)							(LSB)
D7	D6	D5	D4	D3	D2	D1	D0
NV	NV	NV	NV	NV	NV	NV	NV





Write in Process

The contents of the Data Registers are saved to nonvolatile memory when the \overline{CS} pin goes from LOW to HIGH after a complete write sequence is received by the device. The progress of this internal write operation can be monitored by a write in process bit (WIP). The WIP bit is read with a read status command.

INSTRUCTIONS

Identification (ID) Byte

The first byte sent to the X9250 from the host, following a \overline{CS} going HIGH to LOW, is called the Identification byte. The most significant four bits of the slave address are a device type identifier, for the X9250 this is fixed as 0101[B] (refer to Figure 2).

The two least significant bits in the ID byte select one of four devices on the bus. The physical device address is defined by the state of the $A_0 - A_1$ input pins. The X9250 compares the serial data stream with the address input state; a successful compare of both address bits is required for the X9250 to successfully continue the command sequence. The $A_0 - A_1$ inputs can be actively driven by CMOS input signals or tied to V_{CC} or V_{SS} .

The remaining two bits in the slave byte must be set to 0.

Figure 2. Identification Byte Format



Instruction Byte

The next byte sent to the X9250 contains the instruction and register pointer information. The four most significant bits are the instruction. The next four bits point to one of the four pots and, when applicable, they point to one of four associated registers. The format is shown below in Figure 3.

Figure 3. Instruction Byte Format



The four high order bits of the instruction byte specify the operation. The next two bits (R_1 and R_0) select one of the four registers that is to be acted upon when a register oriented instruction is issued. The last two bits (P1 and P₀) selects which one of the four potentiometers is to be affected by the instruction.

Four of the ten instructions are two bytes in length and end with the transmission of the instruction byte. These instructions are:

- <u>XFR Data Register to Wiper Counter Register</u>—This transfers the contents of one specified Data Register to the associated Wiper Counter Register.
- <u>XFR Wiper Counter Register to Data Register</u>—This transfers the contents of the specified Wiper Counter Register to the specified associated Data Register.
- <u>Global XFR Data Register to Wiper Counter Regiter</u> This transfers the contents of all specified Data Registers to the associated Wiper Counter Registers.
- <u>Global XFR Wiper Counter Register to Data Regiter</u> This transfers the contents of all Wiper Counter Registers to the specified associated Data Registers.

The basic sequence of the two byte instructions is illustrated in Figure 4. These two-byte instructions exchange data between the WCR and one of the Data Registers. A transfer from a Data Register to a WCR is essentially a write to a static RAM, with the static RAM controlling the wiper position. The response of the wiper to this action will be delayed by t_{WRL} . A transfer from the WCR (current wiper position), to a Data Register is a write to nonvolatile memory and takes a minimum of t_{WR} to complete. The transfer can occur between one of the four potentiometers and one of its associated registers; or it may occur globally, where the transfer occurs between all potentiometers and one associated register.

Five instructions require a three-byte sequence to complete. These instructions transfer data between the host and the X9250; either between the host and one of the data registers or directly between the host and the Wiper Counter Register. These instructions are:

- <u>Read Wiper Counter Register</u>—read the current wiper position of the selected pot,
- <u>Write Wiper Counter Register</u>—change current wiper position of the selected pot,
- <u>Read Data Register</u>—read the contents of the selected data register;
- <u>Write Data Register</u>—write a new value to the selected data register.
- <u>Read Status</u>—This command returns the contents of the WIP bit which indicates if the internal write cycle is in progress.

The sequence of these operations is shown in Figure 5 and Figure 6.

The final command is Increment/Decrement. It is different from the other commands, because it's length is indeterminate. Once the command is issued, the master can clock the selected wiper up and/or down in one resistor segment steps; thereby, providing a fine tuning capability to the host. For each SCK clock pulse (t_{HIGH}) while SI is HIGH, the selected wiper will move one resistor segment towards the V_H/R_H terminal. Similarly, for each SCK clock pulse while SI is LOW, the selected wiper will move one resistor segment towards the V_L/R_L terminal. A detailed illustration of the sequence and timing for this operation are shown in Figure 7 and Figure 8.





Figure 5. Three-Byte Instruction Sequence (Write)



Figure 6. Three-Byte Instruction Sequence (Read)



Figure 7. Increment/Decrement Instruction Sequence







Table 1. Instruction Set

			lr	nstru	ction	Set			
Instruction	l ₃	I ₂	I ₁	I ₀	R ₁	R ₀	P ₁	P ₀	Operation
Read Wiper Counter Register	1	0	0	1	0	0	P ₁	P ₀	Read the contents of the Wiper Counter Register pointed to by P_1 - P_0
Write Wiper Counter Register	1	0	1	0	0	0	P ₁	P ₀	Write new value to the Wiper Counter Register pointed to by P_1 - P_0
Read Data Register	1	0	1	1	R ₁	R ₀	P ₁	P ₀	Read the contents of the Data Register pointed to by P_1 - P_0 and R_1 - R_0
Write Data Register	1	1	0	0	R ₁	R ₀	P ₁	P ₀	Write new value to the Data Register pointed to by P_1 - P_0 and R_1 - R_0
XFR Data Register to Wiper Counter Register	1	1	0	1	R ₁	R ₀	P ₁	P ₀	Transfer the contents of the Data Register pointed to by R_1 - R_0 to the Wiper Counter Register pointed to by P_1 - P_0
XFR Wiper Counter Register to Data Register	1	1	1	0	R ₁	R ₀	P ₁	P ₀	Transfer the contents of the Wiper Counter Register pointed to by P_1 - P_0 to the Register pointed to by R_1 - R_0
Global XFR Data Register to Wiper Counter Register	0	0	0	1	R ₁	R ₀	0	0	Transfer the contents of the Data Registers pointed to by R_1 - R_0 of all four pots to their respective Wiper Counter Register
Global XFR Wiper Counter Register to Data Register	1	0	0	0	R ₁	R ₀	0	0	Transfer the contents of all Wiper Counter Registers to their respective data Registers pointed to by R_1 - R_0 of all four pots
Increment/Decrement Wiper Counter Register	0	0	1	0	0	0	P ₁	P ₀	Enable Increment/decrement of the Wiper Counter Register pointed to by P ₁ - P ₀
Read Status (WIP bit)	0	1	0	1	0	0	0	1	Read the status of the internal write cycle, by checking the WIP bit.

Instruction Format

Notes: (1) "A1 ~ A0": stands for the device addresses sent by the master.

- (2) WPx refers to wiper position data in the Counter Register
- (2) "I": stands for the increment operation, SI held HIGH during active SCK phase (high).
- (3) "D": stands for the decrement operation, SI held LOW during active SCK phase (high).

Read Wiper Counter Register(WCR)

CS	de ie	vic den	e ty tifie	pe er	a	dev ddre	vice esse	es	in	istru opc	uctic ode	on 9	a	W ddre	CR esse	es	(s	sent	wip t by	er p X9	oosi 250	tion) on	sc))	CS
Falling Edge	0	1	0	1	0	0	A 1	A 0	1	0	0	1	0	0	P 1	P 0	W P 7	W P 6	W P 5	W P 4	W P 3	W P 2	W P 1	W P 0	Rising Edge

Write Wiper Counter Register (WCR)

CS	de ie	vic den	e ty tifie	pe er	a	dev ddre	vice esse	es	in	istru opc	uctic ode	n	а	W ddr	CR esse	es		(se	D nt b	ata y H	By lost	te on	SI)		CS
Falling Edge	0	1	0	1	0	0	A 1	A 0	1	0	1	0	0	0	P 1	P 0	W P 7	W P 6	W P 5	W P 4	W P 3	W P 2	W P 1	W P 0	Rising Edge

Read Data Register (DR)

	de	vic	e ty	ре		de	vice		in	stru	ictic	n	DF	ano	d W	CR			D	ata	By	te			
CS	i	den	tifie	r	а	ddr	esse	es		орс	ode	;	a	ddre	esse	s	(s	sent	t by	X9	250) on	SC))	CS
Falling Edge	0	1	0	1	0	0	A 1	A 0	1	0	1	1	R 1	R 0	P 1	P 0	W P 7	W P 6	W P 5	W P 4	W P 3	W P 2	W P 1	W P 0	Rising Edge

Write Data Register (DR)

	de	evice	e ty	ре		de	vice		in	stru	ictio	on	DF	R an	d W	CR			D	ata	By	te				
CS	i	den	tifie	er	а	lddr	ess	es	C	эрс	ode)	a	ddre	esse	s		(se	nt b	y h	ost	on	SI)		CS	HIGH-VOLTAGE
Falling Edge	0	1	0	1	0	0	A 1	A 0	1	1	0	0	R 1	R 0	Р 1	P 0	W P 7	W P 6	W P 5	W P 4	W P 3	W P 2	W P 1	W P 0	Rising Edge	WRITE CYCLE

Transfer Data Register (DR) to Wiper Counter Register (WCR)

CS Falling	de i	evic den	e ty tifie	pe er	a	de [:] ddr	vice ess	es	in	stru opc	ictic ode	on 9	DI a	R and addre	d WC	CR s	CS Bising
Edge	0	1	0	1	0	0	A 1	A 0	1	1	0	1	R1	R0	P1	P0	Edge

Transfer Wiper Counter Register (WCR) to Data Register (DR)

CS Falling	de ie	vice den	e ty tifie	pe er	a	de ddr	vice esse	es	in	stru opc	ictic ode	on Ə	DF a	l and ddre	d Wo esse	CR s	CS Rising	HIGH-VOLTAGE
Edge	0	1	0	1	0	0	A 1	A 0	1	1	1	0	R 1	R 0	P 1	P 0	Edge	WRITE CYCLE

Increment/Decrement Wiper Counter Register (WCR)

CS Falling	de i	evice den	e ty tifie	pe r	a	dev ddre	vice esse	es	in	stru opc	ictic ode	on e	a	W0 ddre	CR esse	es		incr (ser	eme it by	ent/ ma	dec aste	ren r oi	nent n SI)		CS Rising
Edge	0	1	0	1	0	0	A 1	A 0	0	0	1	0	Х	Х	Р 1	P 0	I/D	I/D		•		•	I/D	I/D	Edge

Global Transfer Data Register (DR) to Wiper Counter Register (WCR)

	de i	evico den	e ty tifie	pe r	a	dev ddre	vice esse	es	in	istru opc	ictic ode	n	a	D ddre	R esse	es	CS Bising
Edge	0	1	0	1	0	0	A 1	A 0	0	0	0	1	R 1	R 0	0	0	Edge

Global Transfer Wiper Counter Register (WCR) to Data Register (DR)

	de	vic	e ty	ре		dev	/ice		in	stru	uctio	on		D	R			
CS Falling	io	den	tifie	er	a	ddre	ess	es	(орс	ode	e	ac	ddre	esse	es	CS Risina	HIGH-VOLTAGE
Edge	0	1	0	1	0	0	A 1	A 0	1	0	0	0	R 1	R 0	0	0	Edge	WRITE CYCLE
				1				_			1	1		-				

Read Status

	de i	evic den	e ty tifie	pe er	a	de\ ddre	/ice esse	es	in (stru opc	uctio ode	on 9					(5	sent	D t by	ata X9	By1 250	te) on	SC))	CS
Falling Edge	0	1	0	1	0	0	A 1	A 0	0	1	0	1	0	0	0	1	0	0	0	0	0	0	0	W I P	Rising Edge

ABSOLUTE MAXIMUM RATINGS

Temperature under bias	65 to +135°C
Storage temperature	65 to +150°C
Voltage on SCK, SCL or any address in	nput
with respect to V _{SS}	1V to +7V
Voltage on V+ (referenced to V _{SS})	10V
Voltage on V- (referenced to V _{SS})	10V
(V+) - (V-)	12V
Any V _H /R _H	V+
Any VL/RL	V-
Lead temperature (soldering, 10s)	300°C
I _W (10s)	±15mA

COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device (at these or any other conditions above those listed in the operational sections of this specification) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Temp	Min.	Max.
Commercial	0°C	+70°C
Industrial	-40°C	+85°C

Device	Supply Voltage (V _{CC}) Limits ⁽⁴⁾
X9250	5V ± 10%
X9250-2.7	2.7V to 5.5V

POTENTIOMETER CHARACTERISTICS (Over recommended operating conditions unless otherwise stated.)

				Lin	nits		
Symbol	Paramet	ter	Min.	Тур.	Max.	Unit	Test Conditions
	End to end resistance			±20	%		
	Power rating				50	mW	25°C, each pot
IW	Wiper current				±7.5	mA	
RW	Wiper resistance			150	250	Ω	Wiper current = $\pm 1mA$
Vv+	Voltage on V+ pin	X9250	+4.5		+5.5	V	
		X9250-2.7	+2.7		+5.5		
Vv-	Voltage on V- pin	X9250	-5.5		-4.5	V	
		X9250-2.7	-5.5		-2.7		
V _{TERM}	Voltage on any V _H /R	H or VL/RL pin	V-		V+	V	
	Noise			-120		dBV	Ref: 1kHz
	Resolution ⁽⁴⁾			0.6		%	
	Absolute linearity (1)				±1	MI ⁽³⁾	V _{w(n)(actual)} - V _{w(n)(expected)}
	Relative linearity ⁽²⁾				±0.6	MI ⁽³⁾	$V_{w(n + 1 - [V_{w(n) + MI}]}$
	Temperature coefficie	ent of R _{TOTAL}		±300		ppm/°C	
	Ratiometric Tempera Coefficient			±20	ppm/°C		
C _H /C _L /C _W	Potentiometer Capac	itances		10/10/25		pF	See Circuit #3

Notes: (1) Absolute linearity is utilized to determine actual wiper voltage versus expected voltage as determined by wiper position when used as a potentiometer.

(2) Relative linearity is utilized to determine the actual change in voltage between two successive tap positions when used as a potentiometer. It is a measure of the error in step size.

(3) MI = RTOT/255 or $(V_H/R_H - V_L/R_L)/255$, single pot

(4) Individual array resolutions.

			Li	mits		
Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
ICC1	V _{CC} supply current (active)			400	μA	f _{SCK} = 2MHz, SO = Open, Other Inputs = V _{SS}
I _{CC2}	V _{CC} supply current (nonvolatile write)			1	mA	f _{SCK} = 2MHz, SO = Open, Other Inputs = V _{SS}
I _{SB}	V _{CC} current (standby)			5	μA	SCK = SI = V_{SS} , Addr. = V_{SS}
ILI	Input leakage current			10	μA	$V_{IN} = V_{SS}$ to V_{CC}
ILO	Output leakage current			10	μA	$V_{OUT} = V_{SS}$ to V_{CC}
VIH	Input HIGH voltage	V _{CC} x 0.7		V _{CC} + 0.1	V	
V _{IL}	Input LOW voltage	-0.5		V _{CC} x 0.3	V	
V _{OL}	Output LOW voltage			0.4	V	I _{OL} = 3mA

D.C. OPERATING CHARACTERISTICS (Over the recommended operating conditions unless otherwise specified.)

ENDURANCE AND DATA RETENTION

Parameter	Min.	Unit
Minimum endurance	100,000	Data changes per bit per register
Data retention	100	Years

CAPACITANCE

Symbol	Test	Max.	Unit	Test Conditions
C _{OUT} ⁽⁵⁾	Output capacitance (SO)	8	pF	$V_{OUT} = 0V$
C _{IN} ⁽⁵⁾	Input capacitance (A0, A1, SI, and SCK, CS)	6	pF	$V_{IN} = 0V$

POWER-UP TIMING

Symbol	Parameter	Min.	Max.	Unit
^t PUR ⁽⁶⁾	Power-up to initiation of read operation		1	ms
^t PUW ⁽⁶⁾	Power-up to initiation of write operation		5	ms
t _R V _{CC} ⁽⁷⁾	V _{CC} power up ramp rate	0.2	50	V/msec

POWER UP AND DOWN REQUIREMENT

The are no restrictions on the sequencing of the bias supplies V_{CC} , V+, and V- provided that all three supplies reach their final values within 1msec of each other. At all times, the voltages on the potentiometer pins must be less than V+ and more than V-. The recall of the wiper position from nonvolatile memory is not in effect until all supplies reach their final value. The V_{CC} ramp rate spec is always in effect.

Notes: (5) This parameter is periodically sampled and not 100% tested

- (6) t_{PUR} and t_{PUW} are the delays required from the time the third (last) power supply (V_{CC}, V+ or V-) is stable until the specific instruction can be issued. These parameters are periodically sampled and not 100% tested.
- (7) Sample tested only.

A.C. TEST CONDITIONS

Input pulse levels	V _{CC} x 0.1 to V _{CC} x 0.9
Input rise and fall times	10ns
Input and output timing level	V _{CC} x 0.5

Circuit #3 SPICE Macro Model



EQUIVALENT A.C. LOAD CIRCUIT



AC TIMING

Symbol	Parameter	Min.	Max.	Unit
fscк	SSI/SPI clock frequency		2.0	MHz
tCYC	SSI/SPI clock cycle time	500		ns
twн	SSI/SPI clock high time	200		ns
twL	SSI/SPI clock low time	200		ns
^t LEAD	Lead time	250		ns
^t LAG	Lag time	250		ns
ts∪	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input setup time	50		ns
t _H	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input hold time	75		ns
t _{RI}	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input rise time		2	μs
t _{FI}	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input fall time		2	μs
t _{DIS}	SO output disable Time	0	500	ns
t _V	SO output valid time		100	ns
tно	SO output hold time	0		ns
t _{RO}	SO output rise time		50	ns
^t FO	SO output fall time		50	ns
^t HOLD	HOLD time	400		ns
t _{HSU}	HOLD setup time	100		ns
tнн	HOLD hold time	100		ns
^t HZ	HOLD low to output in high Z		100	ns
t _{LZ}	HOLD high to output in low Z		100	ns
Τ _Ι	Noise suppression time constant at SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ inputs		TBD	ns
tcs	CS deselect time	2		μs
tWPASU	WP, A0 and A1 setup time	0		ns
^t WPAH	WP, A0 and A1 hold time	0		ns

HIGH-VOLTAGE WRITE CYCLE TIMING

Symbol	Parameter	Тур.	Max.	Unit
^t WR	High-voltage write cycle time (store instructions)	5	10	ms

XDCP TIMING

Symbol	Parameter	Min.	Max.	Unit
twrpo	Wiper response time after the third (last) power supply is stable		10	μs
twrL	Wiper response time after instruction issued (all load instructions)		10	μs
twrid	Wiper response time from an active SCL/SCK edge (increment/decrement instruc- tion)		40	μs

SYMBOL TABLE

WAVEFORM	INPUTS	OUTPUTS
	Must be steady	Will be steady
	May change from Low to High	Will change from Low to High
	May change from High to Low	Will change from High to Low
	Don't Care: Changes Allowed	Changing: State Not Known
	N/A	Center Line is High Impedance

TIMING DIAGRAMS

Input Timing



Output Timing



Hold Timing



XDCP Timing (for all Load Instructions)



XDCP Timing (for Increment/Decrement Instruction)



Write Protect and Device Address Pins Timing



APPLICATIONS INFORMATION

Basic Configurations of Electronic Potentiometers



Three terminal Potentiometer; Variable voltage divider



Two terminal Variable Resistor; Variable current

Application Circuits

Noninverting Amplifier



Voltage Regulator





Offset Voltage Adjustment



Comparator with Hysterisis



Application Circuits (continued)





Inverting Amplifier



Equivalent L-R Circuit







 $\begin{array}{l} \mbox{frequency} \propto R_1,\,R_2,\,C \\ \mbox{amplitude} \propto R_A,\,R_B \end{array}$

TSSOP Package Outline Drawing



NOTE: The package drawing shown here may not be the latest version. To check the latest revision, please refer to the Intersil website at http://www.intersil.com/design/packages/index.asp

Small Outline Plastic Packages (SOIC)



NOTES:

- 1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. The lead width "B", as measured 0.36mm (0.014 inch) or greater
- above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M24.3 (JEDEC MS-013-AD ISSUE C) 24 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

	INC	HES	MILLIN	IETERS	
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
В	0.013	0.020	0.33	0.51	9
С	0.0091	0.0125	0.23	0.32	-
D	0.5985	0.6141	15.20	15.60	3
E	0.2914	0.2992	7.40	7.60	4
е	0.05	BSC	1.27 BSC		-
Н	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
Ν	24		2	24	7
α	0°	8°	0°	8°	-

Rev. 1 4/06

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Device Information

X9250

Printer Friendly Version

Quad Digitally Controlled Potentiometer (XDCP™)

DS Datasheets,	Description	<u>Key</u>	PT Parametric	Related
Related Docs		Features	Data	Devices
& Simulations				

Ordering Information

RoHS/Pb-Free/Green Device

Part No.	Design-In Status	Temp.	Package	MSL	Price US \$		
X9250TS24	Active	Comm	24 Ld SOIC	5	5.20	Buy	
X9250TS24-2.7	Active	Comm	24 Ld SOIC	3	5.73	Buy	
X9250TS24-2.7T1	Active	Comm	24 Ld SOIC T+R	5	5.73	Buy	
X9250TS24I	Active	Ind	24 Ld SOIC	5	6.51	Buy	
X9250TS24I-2.7	Active	Ind	24 Ld SOIC	5	7.16	Buy	Sample
X9250TS24I-2.7T1	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250TS24I-2.7T2	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250TS24IT1	Active	Ind	24 Ld SOIC T+R	5	6.51	Buy	
X9250TS24IZ-2.7 🔁	Active	Ind	24 Ld SOIC	5	7.16	Buy	
X9250TS24IZ-2.7T1 🔁	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250TS24IZ-2.7T2 🔨	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250TS24T1	Active	Comm	24 Ld SOIC T+R	5	5.20	Buy	
X9250TS24Z 🔁	Active	Comm	24 Ld SOIC	5	5.20	Buy	
X9250TS24Z-2.7 🔁	Active	Comm	24 Ld SOIC	5	5.73	Buy	
X9250TS24Z-2.7T1 🔁	Active	Comm	24 Ld SOIC T+R	5	5.73	Buy	
X9250TS24ZT1 🔁	Active	Comm	24 Ld SOIC T+R	5	5.20	Buy	
X9250TV24	Active	Comm	24 Ld TSSOP	1	5.46	Buy	
X9250TV24-2.7	Active	Comm	24 Ld TSSOP	1	6.01	Buy	
X9250TV24I	Active	Ind	24 Ld TSSOP	1	6.83	Buy	
X9250TV24I-2.7	Active	Ind	24 Ld TSSOP	1	7.52	Buy	
X9250US24	Active	Comm	24 Ld SOIC	5	5.20	Buy	
X9250US24-2.7	Active	Comm	24 Ld SOIC	5	5.73	Buy	Sample
X9250US24-2.7T1	Active	Comm	24 Ld SOIC T+R	5	5.73	Buy	
X9250US24I	Active	Ind	24 Ld SOIC	5	6.51	Buy	
X9250US24I-2.7	Active	Ind	24 Ld SOIC	5	7.16	Buy	
X9250US24I-2.7T1	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250US24I-2.7T2	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250US24IT1	Active	Ind	24 Ld SOIC T+R	5	6.51	Buy	
X9250US24IZ-2.7 🖲	Active	Ind	24 Ld SOIC	5	7.16	Buy	
X9250US24IZ-2.7T1 🔁	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250US24IZ-2.7T2 🔁	Active	Ind	24 Ld SOIC T+R	5	7.16	Buy	
X9250US24T1	Active	Comm	24 Ld SOIC T+R	5	5.20	Buy	
X9250US24Z 🔁	Active	Comm	24 Ld SOIC	5	5.20	Buy	

X9250US24Z-2.7 🐯	Active	Comm	24 Ld SOIC	5	5.73	Buy	
X9250US24Z-2.7T1 🔁	Active	Comm	24 Ld SOIC T+R	5	5.73	Buy	
X9250US24ZT1 🔁	Active	Comm	24 Ld SOIC T+R	5	5.20	Buy	1
X9250UV24	Active	Comm	24 Ld TSSOP	1	5.46	Buy	
X9250UV24-2.7	Active	Comm	24 Ld TSSOP	1	6.01	Buy	
X9250UV24-2.7A	Active	Comm	24 Ld TSSOP	1	6.01	Buy	1
X9250UV24I	Active	Ind	24 Ld TSSOP	1	6.83	Buy	1
X9250UV24I-2.7	Active	Ind	24 Ld TSSOP	1	7.52	Buy	1
X9250UV24IZ 🔨	Active	Ind	24 Ld TSSOP	5	6.83	Buy	
X9250UV24IZ-2.7 🔁	Active	Ind	24 Ld TSSOP	5	7.52	Buy	
X9250UV24IZ-2.7T2 🔁	Active	Ind	24 Ld TSSOP T+R	5	7.52	Buy	1
XLABVIEW01	Active			N/A	91.77	Buy	Sam
XLABVIEW01Z 🔁	Active		Eval Board	N/A	91.77	Buy	
X9250TS24IZ 🔁	Coming Soon	Ind	24 Ld SOIC	3	6.49		
X9250TV24IZ 🔁	Coming Soon	Ind	24 Ld TSSOP	3			
X9250TV24IZ-2.7 🔁	Coming Soon	Ind	24 Ld TSSOP	3			
X9250US24IZ 🔁	Coming Soon	Ind	24 Ld SOIC	3	6.49		
X9250UV24Z-2.7 🔁	Coming Soon	Comm	24 Ld TSSOP	3			
X9250TS24IZT1 🔁	InActive	Ind	24 Ld SOIC T+R	3	6.49		
X9250TV24Z 😰	InActive	Comm	24 Ld TSSOP	3			
X9250TV24Z-2.7 🔁	InActive	Comm	24 Ld TSSOP	3			
X9250TZ24I-2.7	InActive	Ind	24 Ld TSSOP	N/A			
X9250TZ24I-2.7T2	InActive	Ind	24 Ld TSSOP	3			
X9250US24IZT1 🖲	InActive	Ind	24 Ld SOIC T+R	3	6.49		
X9250UV24Z 🔁	InActive	Comm	24 Ld TSSOP	3			
X9250UZ24I-2.7	InActive	Ind	24 Ld TSSOP	N/A			
X9250UZ24I-2.7T1	InActive	Ind	24 Ld TSSOP T+R	N/A			

The price listed is the manufacturer's suggested retail price for quantities between 100 and 999 units. However, prices in today's market are fluid and may change without notice.

MSL = Moisture Sensitivity Level - per IPC/JEDEC J-STD-020

SMD = Standard Microcircuit Drawing

Description

The X9250 integrates 4 digitally controlled potentiometers (XDCP) on a monolithic CMOS integrated circuit.

The digitally controlled potentiometer is implemented using 255 resistive elements in a series array. Between each element are tap points connected to the wiper terminal through switches. The position of the wiper on the array is controlled by the user through the SPI bus interface. Each potentiometer has associated with it a volatile Wiper Counter Register (WCR) and 4 nonvolatile Data Registers (DR0:DR3) that can be directly written to and read by the user. The contents of the WCR controls the position of the wiper on the resistor array though the switches. Power up recalls the contents of DR0 to the WCR.

The XDCP can be used as a three-terminal potentiometer or as a two-terminal variable resistor in a wide variety of applications including control, parameter adjustments, and signal processing.

Key Features

- Four potentiometers in one package
- 256 resistor taps/pot 0.4% resolution

- SPI serial interface
- Wiper resistance, 40Ω typical @ V_{CC} = 5V
- Four nonvolatile data registers for each pot
- Nonvolatile storage of wiper position
- Standby current < 5µA max (total package)
- Power supplies
 - V_{CC} = 2.7V to 5.5V
 - V+ = 2.7V to 5.5V
 - V- = -2.7V to -5.5V
- 100kΩ, 50kΩ total pot resistance
- High reliability
 - Endurance 100,000 data changes per bit per register
 - Register data retention 100 years
- 24 Ld SOIC, 24 Ld TSSOP
- Dual supply version of X9251
- Pb-free plus anneal available (RoHS compliant)

Related Documentation

Application Note(s):

- <u>A Compendium of Application Circuits for Intersil's Digitally-Controlled (XDCP)</u>
 <u>Potentiometers</u>
- <u>A Primer on Digitally-Controlled Potentiometers</u>
- <u>Application of Intersil Digitally Controlled Potentiometers (XDCP™) as Hybrid Analog/Digital</u> <u>Feedback System Control Elements</u>
- DC/DC Module Trim with Digital Potentiometers
- Designing Power Supplies Using Intersil's XDCP Mixed Signal Products
- Power Supply and DC to DC Converter Control using Intersil Digitally Controlled Potentiontiometers (XDCPs)
- Putting Analog On The Bus
- Shaft Encoder Drives Multiple Intersil Digitally Controlled Potentiontiometers (XDCPs)
- Tone, Balance, and Volume Control using a Quad XDCP
- Using Intersil Digitally Controlled Potentiometers in Commercial RF Power Amplifier <u>Applications</u>



Low Noise/Low Power/SPI Bus/256 Taps

Technical Brief(s):

- <u>Converting a Fixed PWM to an Adjustable PWM</u>
- EV Evaluation Board(s):
 - Intersil_XDCP_Test_Utility_Manual_rev_3.2.3.pdf
 - LabView_XDCP_Software.zip
 - LabView_XDCP_Upgrade_3.2.3.zip
 - <u>Readme_XicorLabVIEW_V3.2.3.txt</u>
 - XDCP_Vref Evaluation Board Kit Documentation and Software
 - <u>accessHW.zip</u>

Technical Homepage:

- Digitally Controlled Potentiometers (DCPs) and Capacitors (DCCs)
- Precision Analog Homepage

PT Parametric Data

Number of DCPs	Quad
Number of Taps	256
Memory Type	Non-Volatile
Bus Interface Type	SPI
Resistance Options (kΩ)	50, 100
V _{CC} Range (V)	2.7 to 5.5
DCP Bias Range (V)	-10, +10
DCP Differential Terminal Voltage (V)	10
V+, V- Supply Range (V)	2.7 to 5.5 and -5.5 to -2.7
Terminal Voltage Range V_L to V_H (V)	V- to V+
Resistance Taper	Linear
Wiper Current (mA)	±3
Wiper Resistance (Ω)	150
Standby Current I _{SB} (µA)	5

Related	Devices
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ISL22343	Quad Digitally Controlled Potentiometer (XDCP™), Low Noise, Low Power, I ² C® Bus, 256 Taps
ISL22444	Quad Digitally Controlled Potentiometer (XDCP™), Low Noise, Low Power, SPI® Bus, 256 Taps
<u>X9251</u>	Quad Digitally-Controlled (XDCP™) Potentiometer
<u>X9252</u>	Quad Digitally-Controlled (XDCP™) Potentiometer
<u>X9258</u>	Low Noise, Low Power, 2-Wire Bus, 256 Taps Quad Digital Controlled Potentiometer (XDCP™)
<u>X9259</u>	Quad Digitally Controlled (XDCP™)Potentiometers
<u>X95840</u>	Quad Digital Controlled Potentionmeters (XDCP™); Low Noise/Low Power/I ² C® Bus/256 Taps

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PT Parametric Table

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